Helical quantum Hall phase in graphene on SrTiO3

Benjamin Sacépé¹

Louis Veyrat¹, Corentin Deprez¹, Alexis Coissard¹, Xiaoxi Li², Frédéric Gay¹, Kenji Watanabe³, Takashi Taniguchi³, Zheng Han², Benjamin Piot⁴, Hermann, Sellier¹ ¹Université Grenoble Alpes, CNRS, Grenoble INP, Institut Néel, 38000 Grenoble, France ²Shenyang National Laboratory for Materials Science, Institute of Metal Research, Chinese Academy of Sciences, Shenyang 110016, P. R. China ³National Institute for Materials Science, 1-1 Namiki, Tsukuba 306-0044, Japan ⁴Université Grenoble Alpes, UPS-INSA-EMFL-CNRS-LNCMI, 38000 Grenoble, France Benjamin.sacepe@neel.cnrs.fr

In this talk I will present a new strategy to induce a helical phase in graphene constructed on the basis of the quantum Hall effect. I will show that the ground state of charge neutral graphene under perpendicular magnetic field can be tuned in a quantum Hall topological insulator state with a ferromagnetic order that exhibits spin-filtered, helical edge channels. This topological phase emerges in the graphene zeroth Landau level via a suitable screening of the Coulomb interaction by a SrTiO₃ high-k dielectric substrate. We observed robust helical edge transport emerging at a magnetic field as low as 1 T and withstanding temperatures up to 110 K over micron-long distances. This new and versatile graphene platform opens up a promising avenue for topological superconductivity.

References

[1] L. Veyrat, C. Déprez, A. Alexis, X. Li, F. Gay, K. Watanabe, T. Taniguchi, Z. Han, B. Piot, H. Sellier, B. Sacépé, Science 367, 781 (2020)

Figures



Figure 1: Spin-filtered helical edge channels propagating on the edge of graphene.